Tomography and manipulation of quantum Hall edge channels by Scanning Gate Microscopy

<u>N. Paradiso</u>

Scuola Normale Superiore di Pisa

Discussione della Tesi di Perfezionamento



Advisors

Prof. F. Beltram, dr. S. Heun

Co-workers

- NEST, Pisa, Italy: S. Roddaro, L. Sorba
- TASC, Trieste, Italy: G. Biasiol

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The road to quantum computing



The road to quantum computing



Why a quantum Hall quantum Computer?

Fundamental reasons: QH liquids at peculiar filling factors (5/2, 12/5) are expected to **exhibit non-Abelian excitations**. Since quantum operations on such objects are expected to only depend on the **topology**, they could implement **fault tolerant calculations**. [Nayak *et al.*, Rev. Mod. Phys. **80**, 1083.]

REVIEWS OF MODERN PHYSICS, VOLUME 80, JULY-SEPTEMBER 2008

Non-Abelian anyons and topological quantum computation



a gate "NOT" operating with non-Abelian quasiparticles

[Nayak et al., Rev. Mod. Phys. 80, 1083 (2003)]



Proposal for Production and Detection of Entangled Electron-Hole Pairs in a Degenerate Electron Gas

Practical reasons: highly coherent,

dissipationless transport by means of chiral **1D channels**

- Solid state devices.
- Chiral channels insensitive to backscattering.
- Single-fermion source
- Perfect transmission

 Accurate control of the chemical potential, tunnel probability, and occupation distribution of individual channels

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High design flexibility

The non-interacting picture of the QH effect



The non-interacting picture of the QH effect



• Edge state picture: *current is carried by chiral 1D channels*



Roddaro et al.: PRL **90** (2003) 046805 Roddaro et al.: PRL **93** (2004) 046801 Roddaro et al.: PRL **95** (2005) 156804 Roddaro, Paradiso et al.: PRL **103** (2009) 016802

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Edge channel-based interferometers

The very large coherence length has been exploited to implement complex interferometers as the electronic Mach-Zehnder.

Puzzle: so far, MZI only work with electron-like excitations. The interference of fractional quasiparticles is inexplicably still elusive

An electronic Mach–Zehnder interferometer

Yang Ji, Yunchul Chung, D. Sprinzak, M. Heiblum, D. Mahalu & Hadas Shtrikman



MG2

Ji et al.: Nature **422**, 415 (2003)

Preamp

MG1

а

b

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Fractional structures in integer edges

Our first transport measurements found evidences of fractional structures (Luttinger liquid-like) in a single edge (Fermi liquid).





-S. Roddaro, <u>N. Paradiso</u>, et al: "Tuning Nonlinear Charge Transport between Integer and Fractional Quantum Hall States"; Phys. Rev. Lett. **103**, (2009) 016802.

Need for spatially resolved measurements

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Non-interacting VS interacting picture

• The self consistent potential due to e-e interactions modifies the edge structure

•For any realistic potential the density goes smoothly to zero.

•Alternating compressible and incompressible stripes arise at the sample edge

Incompressible stripes: •The electron density is constant •The potential has a jump

Compressible stripes: •The electron density has a jump •The potential is constant ←



Edge channel tomography by SGM

SGM technique: we select individual channels from the edge of a quantized 2DEG, we send them to the constriction and make them backscatter with the biased SGM tip.



- Bulk filling factor v=4
- B = 3.04 T
- 2 spin-degenerate edge channels
- gate-region filling factors g₁ = g₂ = 0







N. Paradiso et al., Physica E 42 (2010) 1038.

tip position (µm)

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Imaging fractional structures in integer channels



The Reconstruction Picture suggests that at the edge of a smooth **integer** edge a series of compressible/ **incompressible fractional stripes** can occur. We used the SGM technique to image them.

N. Paradiso *et al.* Phys. Rev. Lett. 108, 246801 (2012)

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Fractional edge reconstruction



Fractional edge reconstruction

The IS width values (colored dots àæòî) obtained from SGM images compare well with the reconstruction picture predictions



Can we exploit the non-trivial edge structure?



The state of the art of electronic quantum interferometry

D1

At the **beam splitters** the electrons are backscattered into the **counterpropagating edge** through two quantum point contacts (QPCs)

An electronic Mach–Zehnder interferometer

Yang Ji, Yunchul Chung, D. Sprinzak, M. Heiblum, D. Mahalu & Hadas Shtrikman



BS1

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we induce backscattering by reducing this distance



A new architecture for QH interferometry

a simply connected QH interferometer: the proposal of *Giovannetti et al.*

PHYSICAL REVIEW B 77, 155320 (2008)

Multichannel architecture for electronic quantum Hall interferometry

Vittorio Giovannetti,¹ Fabio Taddei,¹ Diego Frustaglia,² and Rosario Fazio^{1,3}



New architecture: beam splitters induce mixing between co-propagating edge channels

Advantages:

simply connected topology (no air bridges)

•very small Φ area, only a few flux quanta are involved

•the device is scalable: it is possible to put many devices in series

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the only elusive parts are the **beam mixers** between **co-propagating channels**

coherent inter-channel mixing

Is it possible to study and image the microscopic details of the inter-channel scattering?

Studying the inter-channel equilibration

Edge states in the regimes of integer and fractional quantum Hall effects

E V Deviatov

Physics - Uspekhi 50 (2) 197 - 218 (2007)





devices with fixed interaction length *d*: elusive determination of the microscopic details of the equilibration mechanisms



The oppurtunity of the Scanning Gate Microscopy

Our technique allows to selectively control the channel trajectory

Our idea: exploit the mobile depletion spot induced by the SGM to continuously tune *d*



Experimental setup



I_B

÷

Calibration step



Calibration step



Imaging the inter-channel equilibration



SGM map of the I_B signal: direct imaging of the equilibration process.





By grounding the upper contact an imbalance is established between the edges.



Imaging the inter-channel equilibration

The profiles of $G_B(d)$ along the trajectory show a strict dependance on the local details



1.0

0.9

DC bias

Imaging the inter-channel equilibration



Tight binding simulations



Next step: a simply connected MZI



Nonlinear regime



Two mechanisms for the inter-channel scattering



At high bias (Δµ≈ħω_c) vertical transition with photon emission are enabled (threshold and saturation)



$$dI = dx \frac{2e\mathcal{T}_0}{hv_d} \int_{-\infty}^{\infty} (f_{\mu_i,T}(\epsilon) - f_{\mu_o,T}(\epsilon))d\epsilon = dx \frac{2e^2\mathcal{T}_0}{hv_d} \Delta V(x)$$

 $\Delta \mu(\mathbf{x})$

0000

 (\mathbf{a})

$$1.0 \\ 0.0 \\ -1.0 \\ -2.0 \\ -3.0 \\ -5.0 \\ -5.0 \\ -5.0 \\ -7.0 \\ -2.0 \\ -1.5 \\ -1.0 \\ -0.5 \\ 0.0 \\ -2.0 \\ -1.5 \\ -1.0 \\ -0.5 \\ 0.0 \\ -0.5 \\$$

$$dI = dx \frac{2eT_1}{hv_d} \int_{-\infty}^{\infty} [f_{\mu_i,T}(\epsilon)(1 - f_{\mu_o,T}(\epsilon - \hbar\omega_c))]d\epsilon = dx \frac{2eT_1}{hv_d} \left(\frac{e\Delta V(x) - \hbar\omega_c}{1 - e^{\frac{\hbar\omega_c - e\Delta V(x)}{h_BT}}}\right)$$

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Impact of the electron heating

Electron heating due to injection of hot carriers:





The relaxation of hot carriers induces a dramatic temperature increase. This is why the transition is smoothened and the threshold voltage reduced for high *d*

Summary and outlook



Thank you for your attention!

Nicola Paradiso

Scuola Normale Superiore, Pisa nicola.paradiso@sns.it

How everything began... [LT-AFM installation, Pisa, October 2007]

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